L	Hits	Search Text	DB	Time stamp
Number				
1	26626	semiconductor and (tft or (thin adj film	USPAT;	2004/01/06
		adj transistor))	US-PGPUB;	08:46
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	2485	semiconductor and (tft or (thin adj film	USPAT;	2004/01/06
	i	adj transistor))) and gate and drain and	US-PGPUB;	08:47
		source and offset	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
3	341	((semiconductor and (tft or (thin adj	USPAT;	2004/01/06
		film adj transistor))) and gate and drain	US-PGPUB;	08:47
		and source and offset) and sidewall	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
4	248	, , ,	USPAT;	2004/01/06
		film adj transistor))) and gate and drain	US-PGPUB;	08:48
		and source and offset) and sidewall) and	EPO; JPO;	
		(gate adj electrode)	DERWENT;	
	0.0	1,77	IBM_TDB	0004/04/05
5	88	((((semiconductor and (tft or (thin adj	USPAT;	2004/01/06
		film adj transistor))) and gate and drain	US-PGPUB;	08:48
		and source and offset) and sidewall) and	EPO; JPO;	
		(gate adj electrode)) and (offset adj	DERWENT;	
L	l	region)	IBM TDB	l